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With the principle of "Quality Parts, Customers Priority, Honest Operation, and Considerate Service", our business mainly focus on the distribution of electronic components. Line cards we deal with include Microchip, ALPS, ROHM, Xilinx, Pulse, ON, Everlight and Freescale. Main products comprise IC, Modules, Potentiometer, IC Socket, Relay, Connector. Our parts cover such applications as commercial, industrial, and automotives areas.

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30V DUAL N-CHANNEL ENHANCEMENT MODE MOSFET

Product Summary

BV _{DSS}	R _{DS(ON)} max	I _D max T _A = +25°C		
001/	$22m\Omega @ V_{GS} = 10V$	6.7A		
30V	30mΩ @ V _{GS} = 4.5V	5.2A		

Description and Applications

This MOSFET has been designed to minimize the on-state resistance $(R_{DS(ON)})$ and yet maintain superior switching performance, making it ideal for high efficiency power management applications.

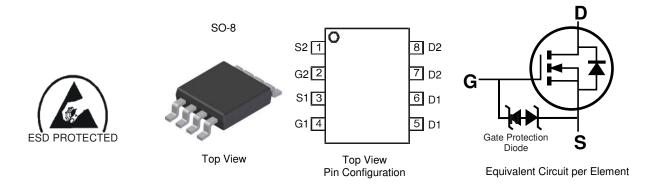
- Backlighting
- Power Management Functions
- DC-DC Converters

Features

- Low On-Resistance
- 100% UIS (Avalanche) Rated
- ESD Protected Gate
- Totally Lead-Free & Fully RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)
- Qualified to AEC-Q101 Standards for High Reliability

Mechanical Data

- Case: SO-8
- Case Material: Molded Plastic, "Green" Molding Compound.
 UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminal Connections Indicator: See Diagram
- Terminals: Finish Matte Tin Annealed over Copper Leadframe. Solderable per MIL-STD-202, Method 208 (3)
- Weight: 0.074 grams (Approximate)



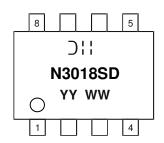
Ordering Information (Note 4)

Part Number	Case	Packaging
DMN3018SSD-13	SO-8	2500/Tape & Reel

Notes:

- 1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS) & 2011/65/EU (RoHS 2) compliant.
- See http://www.diodes.com/quality/lead_free.html for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.
- 3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.
- 4. For packaging details, go to our website at http://www.diodes.com/products/packages.html.

Marking Information



Oll = Manufacturer's Marking
N3018SD = Product Type Marking Code
YYWW = Date Code Marking
YY or YY = Year (ex: 16 = 2016)
WW = Week (01 to 53)



Maximum Ratings (@ $T_A = +25$ °C, unless otherwise specified.)

Characteristic	Symbol	Value	Unit		
Drain-Source Voltage	V_{DSS}	30	V		
Gate-Source Voltage	V_{GSS}	±20	V		
		$T_A = +25^{\circ}C$ $T_A = +70^{\circ}C$	I _D	6.7 5.3	А
Continuous Drain Current (Note 5) V _{GS} = 10V	t < 10s	$T_A = +25$ °C $T_A = +70$ °C	I _D	8.7 6.9	А
Pulsed Drain Current (10μs Pulse, Duty Cycle = 1%	I_{DM}	60	Α		
Maximum Body Diode Continuous Current			Is	2.0	Α
Avalanche Current (Note 6) L = 0.1mH			I _{AR}	19	Α
Repetitive Avalanche Energy (Note 6) L = 0.1mH			E _{AR}	18	mJ

Thermal Characteristics (@T_A = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Unit	
Total Power Dissipation (Note 5)	P_{D}	1.5	W	
Thermal Periotanes, Junatian to Ambient (Note 5)	Steady State	ם	83	°C/W
Thermal Resistance, Junction to Ambient (Note 5)		$R_{\theta JA}$	50	°C/W
Thermal Resistance, Junction to Case (Note 5)	$R_{ heta JC}$	14.5	°C/W	
Operating and Storage Temperature Range	$T_{J_{I}}T_{STG}$	-55 to +150	°C	

Electrical Characteristics (@T_A = +25°C, unless otherwise specified.)

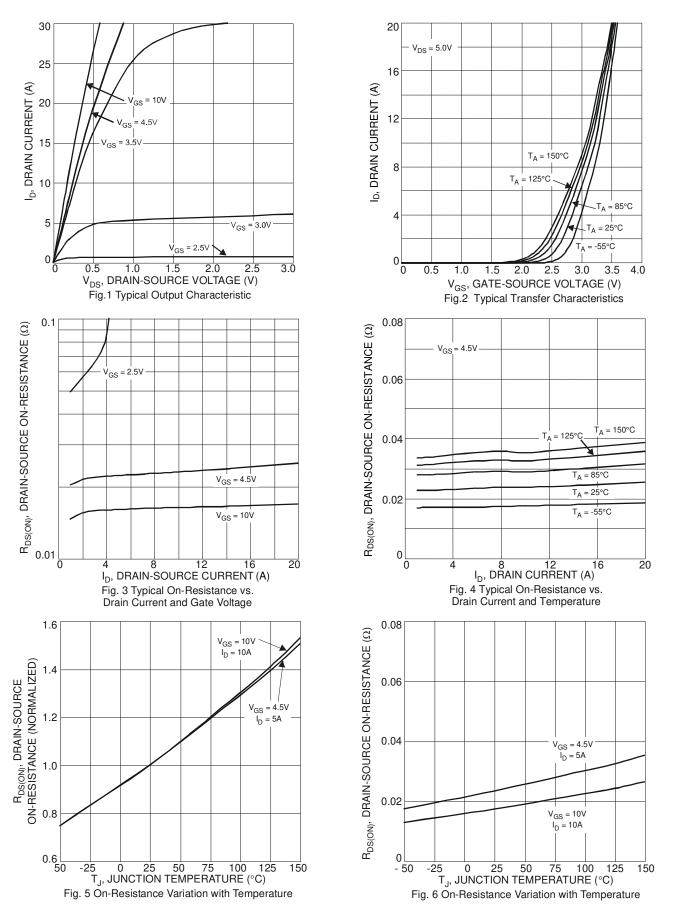
Characteristic	Symbol	Min	Тур	Max	Unit	Test Condition	
OFF CHARACTERISTICS (Note 7)							
Drain-Source Breakdown Voltage	BV _{DSS}	30	_	_	V	$V_{GS} = 0V, I_D = 250\mu A$	
Zero Gate Voltage Drain Current	I _{DSS}	_	_	1	μΑ	$V_{DS} = 24V, V_{GS} = 0V$	
Gate-Source Leakage	I _{GSS}	_	_	±10	μΑ	$V_{GS} = \pm 20V, V_{DS} = 0V$	
ON CHARACTERISTICS (Note 7)							
Gate Threshold Voltage	V _{GS(TH)}	1	1.7	2.1	٧	$V_{DS} = V_{GS}$, $I_D = 250\mu A$	
Static Drain-Source On-Resistance	Dag (a) ii	_	16	22	mΩ	$V_{GS} = 10V, I_D = 10A$	
Static Drain-Source On-Hesistance	R _{DS(ON)}	_	23	30	11177	$V_{GS} = 4.5V, I_D = 6A$	
Forward Transfer Admittance	Y _{fs}	-	8.3	_	S	$V_{DS} = 5V, I_D = 6.9A$	
Diode Forward Voltage	V_{SD}	0.5	_	1.2	٧	$V_{GS} = 0V, I_{S} = 1A$	
DYNAMIC CHARACTERISTICS (Note 8)							
Input Capacitance	C _{iss}	-	697	_		V _{DS} = 15V, V _{GS} = 0V, f = 1.0MHz	
Output Capacitance	Coss	_	97	_	рF		
Reverse Transfer Capacitance	C _{rss}	_	67	_			
Gate Resistance	R_g	_	1.47	_	Ω	$V_{DS} = 0V, V_{GS} = 0V, f = 1.0MHz$	
Total Gate Charge (V _{GS} = 4.5V)	Q_g	_	6.0	_			
Total Gate Charge (V _{GS} = 10V)	Q_g	_	13.2	_	nC	$V_{GS} = 10V, V_{DS} = 15V,$ $I_{D} = 9A$	
Gate-Source Charge	Q_{gs}	_	2.2	_	IIC		
Gate-Drain Charge	Q_{gd}	_	1.8	_			
Turn-On Delay Time	t _{D(ON)}	_	4.3	_			
Turn-On Rise Time	t _R	_	4.4	_		$\begin{split} V_{DD} &= 15V, \ V_{GS} = 10V, \\ R_L &= 15\Omega, \ I_D = 1A, \ R_G = 6\Omega \end{split}$	
Turn-Off Delay Time	t _{D(OFF)}	_	20.1	_	ns		
Turn-Off Fall Time	t _F	_	4.1	_			
Reverse Recovery Time	t _{RR}	_	7.3	_	ns	L = 0.0 di/dt = 500.0/	
Reverse Recovery Charge	Q _{RR}	_	7.9	_	nC	$I_F = 9A$, di/dt = 500A/ μ s	

5. Device mounted on FR-4 substrate PC board, 2oz copper, with 1inch square copper plate.

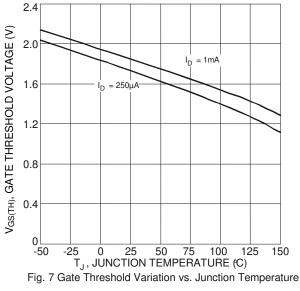
^{6.} I_{AR} and E_{AR} ratings are based on low frequency and duty cycles to keep $T_{J} = +25^{\circ}C$. 7. Short duration pulse test used to minimize self-heating effect.

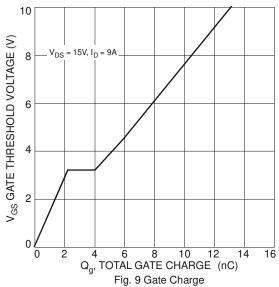
^{8.} Guaranteed by design. Not subject to product testing.

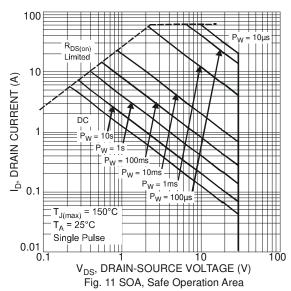


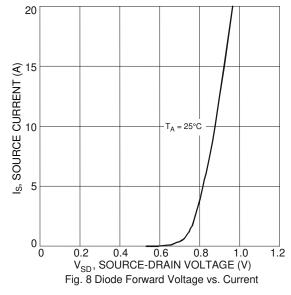


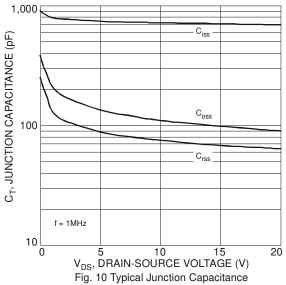




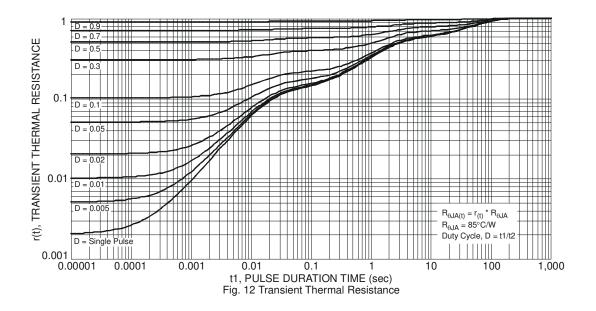






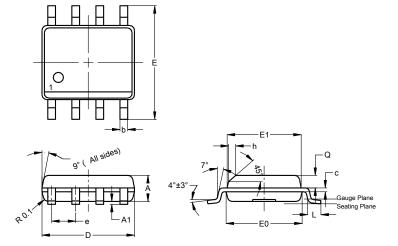






Package Outline Dimensions

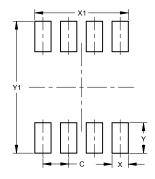
Please see http://www.diodes.com/package-outlines.html for the latest version.



SO-8					
Dim	Min	Max	Тур		
Α	1.40	1.50	1.45		
A1	0.10	0.20	0.15		
b	0.30	0.50	0.40		
С	0.15	0.25	0.20		
D	4.85	4.95	4.90		
Е	5.90	6.10	6.00		
E1	3.80	3.90	3.85		
E0	3.85	3.95	3.90		
е	e 1.2		1.27		
h	-		0.35		
L	0.62	0.82	0.72		
Q	0.60	0.70	0.65		
All	All Dimensions in mm				

Suggested Pad Layout

Please see http://www.diodes.com/package-outlines.html for the latest version.



Dimensions	Value (in mm)			
С	1.27			
Х	0.802			
X1	4.612			
Υ	1.505			
Y1	6.50			



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